



Hanwha Q CELLS Media Statement – Mar. 8, 2019

The patent claims asserted by Hanwha Q CELLS are not restricted to any particular method of manufacture, such as atomic layer deposition (ALD) or plasma-enhanced chemical vapor deposition (PECVD). The infringement claims relating to the '215 patent are directed to solar cell structure with a first dielectric layer including aluminum oxide and a second dielectric layer that contains hydrogen. The patented technology can be applied in many ways. A solar cell employing what is known as Passivated Emitter Rear Cell (PERC) technology is only one type of solar cell that may use technology covered by the '215 patent.

While Hanwha Q CELLS believes it is important to clarify these factual issues, it does not intend to litigate this dispute in the media or to comment further on the substantive legal issues in the case. We look forward to proving our claims in court.

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